MICROCHIP MCP102/103/121/131

Micropower Voltage Supervisors

Features

- Ultra low supply current: 1.75 μA (steady-state max.)
- · Precision monitoring options of:
 - 1.90V, 2.32V, 2.63V, 2.93V, 3.08V, 4.38V and 4.63V
- · Resets microcontroller in a power-loss event
- RST pin (Active-low):
 - MCP121: Active-low, open-drain
 - MCP131: Active-low, open-drain with internal pull-up resistor
- MCP102 and MCP103: Active-low, push-pull
- Reset Delay Timer (120 ms delay, typ.)
- Available in SOT23-3, TO-92 and SC-70 packages
- Temperature Range:
 - Extended: -40°C to +125°C (except MCP1XX-195)
 - Industrial: -40°C to +85°C (MCP1XX-195 only)
- Pb-free devices

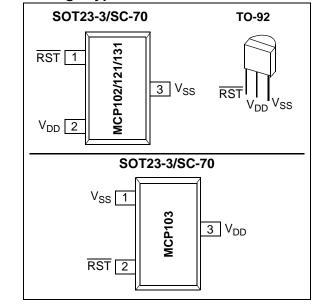
Applications

- Critical Microcontroller and Microprocessor Power-monitoring Applications
- Computers
- Intelligent Instruments
- · Portable Battery-powered Equipment

General Description

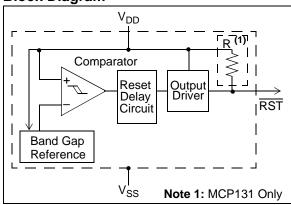
The MCP102/103/121/131 are voltage supervisor devices designed to keep a microcontroller in reset until the system voltage has reached and stabilized at the proper level for reliable system operation. Table 1 shows the available features for these devices.

TABLE 1: DEVICE FEATURES





Package Types



Device	(Output	Reset	Package Pinout	Comment		
Device	Туре	Pull-up Resistor	Delay (typ)	(Pin # 1, 2, 3)	Comment		
MCP102	Push-pull	No	120 ms	RST, V _{DD} , V _{SS}			
MCP103	Push-pull	No	120 ms	Vss, RST, V _{DD}			
MCP121	Open-drain	External	120 ms	RST, V _{DD} , V _{SS}			
MCP131	Open-drain	Internal (~95 kΩ)	120 ms	RST, V _{DD} , V _{SS}			
MCP111	Open-drain	External	No	V_{OUT} , V_{SS} , V_{DD}	See MCP111/112 Data Sheet (DS21889)		
MCP112	Push-Pull	No	No	V_{OUT} , V_{SS} , V_{DD}	See MCP111/112 Data Sheet (DS21889)		

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings†

V _{DD}
Input current (V _{DD})
Output current ($\overline{\text{RST}}$)
Rated Rise Time of V_{DD}
All inputs and outputs (except RST) w.r.t. V _{SS}
0.6V to (V _{DD} + 1.0V)
RST output w.r.t. V _{SS} 0.6V to 13.5V
Storage temperature65°C to + 150°C
Ambient temp. with power applied40°C to + 125°C
Maximum Junction temp. with power applied 150°C
ESD protection on all pins

† Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

DC CHARACTERISTICS

Electrical Specifications: Unless otherwise indicated, all limits are specified for: $V_{DD} = 1V$ to 5.5V, $R_{PU} = 100 \text{ k}\Omega$ (**MCP121** only), $T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$.

14 - 16 - 6 1126 - 6.								
Param	Sym	Min	Тур	Max	Units	Conditions		
Operating Voltage R	lange	V_{DD}	1.0	_	5.5	V		
Specified V _{DD} Value	to RST low	V_{DD}	1.0	_		V	$I_{\overline{RST}} = 10 \text{ uA}, V_{\overline{RST}} < 0.2V$	
Operating Current	MCP102, MCP103,	I _{DD}	_	< 1	1.75	μA	Reset Power-up Timer (t _{RPU}) Inactive	
	MCP121		_	_	20.0	μA	Reset Power-up Timer (t _{RPU}) Active	
	MCP131	I _{DD}	_	< 1	1.75	μA	V _{DD} > V _{TRIP} and Reset Power-up Timer (t _{RPU}) Inactive	
					75	μA	V _{DD} < V _{TRIP} and Reset Power-up Timer (t _{RPU}) Inactive (Note 3)	
			_	_	90	μA	Reset Power-up Timer (t _{RPU}) Active (Note 4)	

- Note 1: Trip point is ±1.5% from typical value.
 - 2: Trip point is $\pm 2.5\%$ from typical value.
 - **3:** RST output is forced low. There is a current through the internal pull-up resistor.
 - 4: This includes the current through the internal pull-up resistor and the reset power-up timer.
 - 5: This specification allows this device to be used in PICmicro® microcontroller applications that require In-Circuit Serial Programming™ (ICSP™) (see device-specific programming specifications for voltage requirements). This specification DOES NOT allow a continuos high voltage to be present on the open-drain output pin (V_{OUT}). The total time that the V_{OUT} pin can be above the maximum device operational voltage (5.5V) is 100s. Current into the V_{OUT} pin should be limited to 2 mA and it is recommended that the device operational temperature be maintained between 0°C to 70°C (+25°C preferred). For additional information, please refer to Figure 2-33.
 - 6: This parameter is established by characterization and not 100% tested.

DC CHARACTERISTICS (CONTINUED)

Electrical Specifications: Unless otherwise indicated, all limits are specified for: $V_{DD} = 1V$ to 5.5V, $R_{PU} = 100 \text{ k}\Omega$ (**MCP121** only), $T_A = -40 \,^{\circ}\text{C}$ to $+125 \,^{\circ}\text{C}$.

Parai	meters	Sym	Min	Тур	Max	Units	Conditions
V _{DD} Trip Point	MCP1XX-195	V_{TRIP}	1.872	1.900	1.929	V	T _A = +25°C (Note 1)
			1.853	1.900	1.948	V	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C (Note 2)}$
	MCP1XX-240		2.285	2.320	2.355	V	T _A = +25°C (Note 1)
			2.262	2.320	2.378	V	Note 2
	MCP1XX-270		2.591	2.630	2.670	V	T _A = +25°C (Note 1)
			2.564	2.630	2.696	V	Note 2
	MCP1XX-300		2.886	2.930	2.974	V	T _A = +25°C (Note 1)
			2.857	2.930	3.003	V	Note 2
	MCP1XX-315		3.034	3.080	3.126	V	T _A = +25°C (Note 1)
			3.003	3.080	3.157	V	Note 2
	MCP1XX-450		4.314	4.380	4.446	V	T _A = +25°C (Note 1)
			4.271	4.380	4.490	V	Note 2
	MCP1XX-475		4.561	4.630	4.700	V	T _A = +25°C (Note 1)
			4.514	4.630	4.746	V	Note 2
V _{DD} Trip Point Tem	рсо	T _{TPCO}	_	±100	_	ppm/°C	
Threshold	MCP1XX-195	V_{HYS}	0.019	_	0.114	V	$T_A = +25$ °C
Hysteresis (min. = 1%,	MCP1XX-240		0.023	_	0.139	V	
max = 6%)	MCP1XX-270		0.026	_	0.158	V	
	MCP1XX-300		0.029	_	0.176	V	
	MCP1XX-315		0.031	_	0.185	V	
	MCP1XX-450		0.044	_	0.263	V	
	MCP1XX-475		0.046	_	0.278	V	
RST Low-level Out	put Voltage	V _{OL}	_	_	0.4	V	$I_{OL} = 500 \mu A$, $V_{DD} = V_{TRIP(MIN)}$
RST High-level Ou (MCP102 and MCI		V _{OH}	V _{DD} – 0.6	1	l	V	I _{OH} = 1 mA, For MCP102/MCP103 only (push-pull output)
Internal Pull-up Re (MCP131 only)	sistor	R _{PU}	_	95	_	kΩ	V _{DD} = 5.5V
Open-drain High Voltage on Output (MCP121 only)		V _{ODH}	_		13.5 ⁽⁵⁾	V	V_{DD} = 3.0V, Time voltage > 5.5V applied \leq 100s, current into pin limited to 2 mA, 25°C operation recommended (Note 5, Note 6)
Open-drain Output (MCP121 only)	Leakage Current	I _{OD}	_	0.1		μA	

Note 1: Trip point is $\pm 1.5\%$ from typical value.

- 2: Trip point is ±2.5% from typical value.
- 3: RST output is forced low. There is a current through the internal pull-up resistor.
- 4: This includes the current through the internal pull-up resistor and the reset power-up timer.
- 5: This specification allows this device to be used in PICmicro® microcontroller applications that require In-Circuit Serial Programming™ (ICSP™) (see device-specific programming specifications for voltage requirements). This specification DOES NOT allow a continuos high voltage to be present on the open-drain output pin (V_{OUT}). The total time that the V_{OUT} pin can be above the maximum device operational voltage (5.5V) is 100s. Current into the V_{OUT} pin should be limited to 2 mA and it is recommended that the device operational temperature be maintained between 0°C to 70°C (+25°C preferred). For additional information, please refer to Figure 2-33.
- **6:** This parameter is established by characterization and not 100% tested.

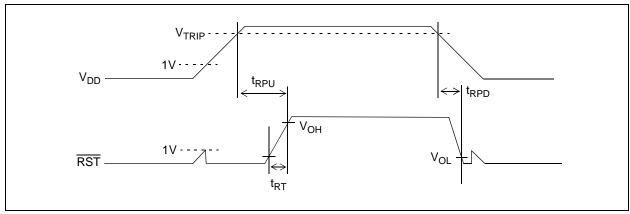


FIGURE 1-1: Timing Diagram.

AC CHARACTERISTICS

Electrical Specifications: Unless otherwise indicated, all limits are specified for: V_{DD} = 1V to 5.5V, R_{PU} = 100 kΩ (MCP121 only), T_{Δ} = -40°C to +125°C.

14 - 40 0 10 1125 0.							
Parameters	Sym	Min	Тур	Max	Units	Conditions	
V _{DD} Detect to RST Inactive	t _{RPU}	80	120	180	ms	Figure 1-1 and C _L = 50 pF	
V _{DD} Detect to RST Active	t _{RPD}	_	130	_	μs	V _{DD} ramped from V _{TRIP(MAX)} + 250 mV down to V _{TRIP(MIN)} - 250 mV, per Figure 1-1 , C _L = 50 p F (Note 1)	
RST Rise Time After RST Active (MCP102 and MCP103 only)	t _{RT}	_	5	_	μs	For RST 10% to 90% of final value per Figure 1-1 , C _L = 50 pF (Note 1)	

Note 1: These parameters are for design guidance only and are not 100% tested.

TEMPERATURE CHARACTERISTICS

Electrical Specifications: Unless otherwise noted, all limits are specified for: $V_{DD} = 1V$ to 5.5V, $R_{PU} = 100 \text{ k}\Omega$ (**MCP121** only), $T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$.

1 A = -40 C to +123 C.								
Parameters	Sym	Min	Тур	Max	Units	Conditions		
Temperature Ranges								
Specified Temperature Range	T _A	-40	_	+85	°C	MCP1XX-195		
Specified Temperature Range	T _A	-40	_	+125	°C	Except MCP1XX-195		
Maximum Junction Temperature	T_J	_		+150	°C			
Storage Temperature Range	T _A	-65	_	+150	°C			
Package Thermal Resistances								
Thermal Resistance, 3L-SOT23	θ_{JA}	_	336	_	°C/W			
Thermal Resistance, 3L-SC-70	θ_{JA}	_	340		°C/W			
Thermal Resistance, 3L-TO-92	θ_{JA}	_	131.9	_	°C/W			

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated, all limits are specified for: V_{DD} = 1V to 5.5V, R_{PU} = 100 k Ω (**MCP121** only; see **Figure 4-1**), T_A = -40°C to +125°C.

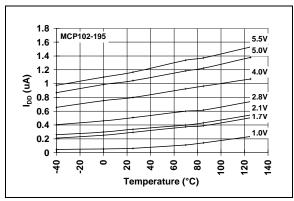


FIGURE 2-1: I_{DD} vs. Temperature (Reset Power-up Timer Inactive) (**MCP102-195**).

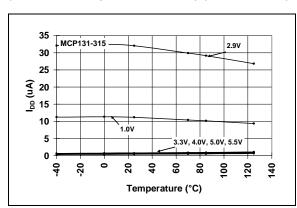


FIGURE 2-2: I_{DD} vs. Temperature (Reset Power-up Timer Inactive) (**MCP131-315**).

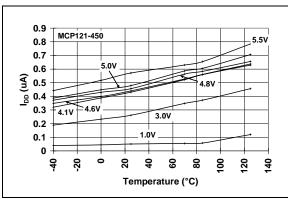


FIGURE 2-3: I_{DD} vs. Temperature (Reset Power-up Timer Inactive) (MCP121-450).

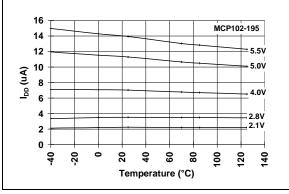


FIGURE 2-4: I_{DD} vs. Temperature (Reset Power-up Timer Active) (MCP102-195).

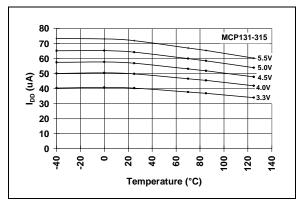


FIGURE 2-5: I_{DD} vs. Temperature (Reset Power-up Timer Active) (MCP131-315).

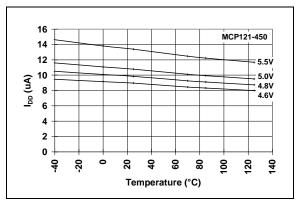


FIGURE 2-6: I_{DD} vs. Temperature (Reset Power-up Timer Active) (**MCP121-450**).

Note: Unless otherwise indicated, all limits are specified for: V_{DD} = 1V to 5.5V, R_{PU} = 100 k Ω (**MCP121** only; see **Figure 4-1**), T_A = -40°C to +125°C.

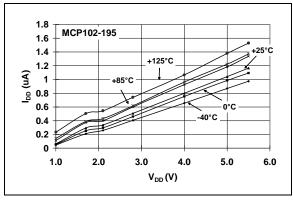


FIGURE 2-7: I_{DD} vs. V_{DD} (Reset Power-up Timer Inactive) (**MCP102-195**).

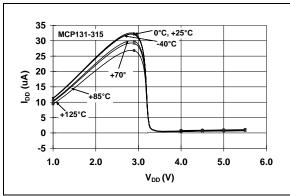


FIGURE 2-8: I_{DD} vs. V_{DD} (Reset Power-up Timer Inactive) (**MCP131-315**).

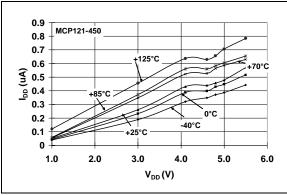


FIGURE 2-9: I_{DD} vs. V_{DD} (Reset Power-up Timer Inactive) (MCP121-450).

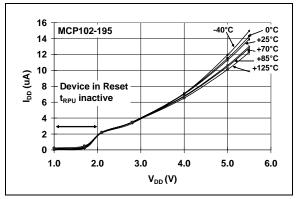


FIGURE 2-10: I_{DD} vs. V_{DD} (Reset Power-up Timer Active) (MCP102-195).

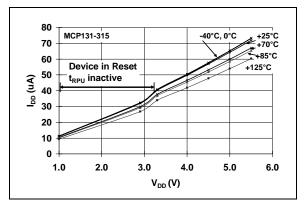


FIGURE 2-11: I_{DD} vs. V_{DD} (Reset Power-up Timer Active) (**MCP131-315**).

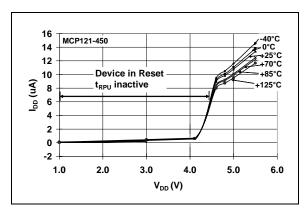


FIGURE 2-12: I_{DD} vs. V_{DD} (Reset Power-up Timer Active) (**MCP121-450**).

Note: Unless otherwise indicated, all limits are specified for: V_{DD} = 1V to 5.5V, R_{PU} = 100 k Ω (**MCP121**; see **Figure 4-1**), T_A = -40°C to +125°C.

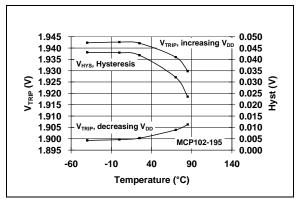


FIGURE 2-13: V_{TRIP} vs. Temperature vs. Hysteresis (**MCP102-195**).

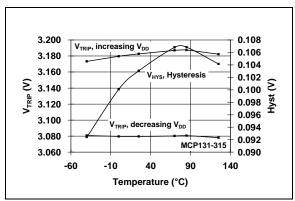


FIGURE 2-14: V_{TRIP} vs. Temperature vs. Hysteresis (**MCP131-315**).

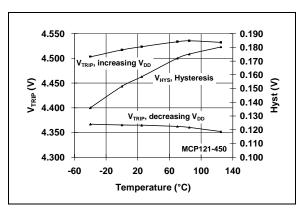


FIGURE 2-15: V_{TRIP} vs. Temperature vs. Hysteresis (**MCP121-450**).

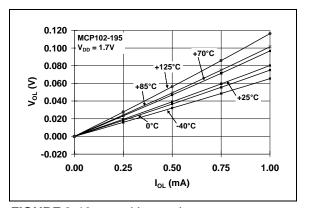


FIGURE 2-16: V_{OL} vs. I_{OL} (MCP102-195 @ $V_{DD} = 1.7V$).

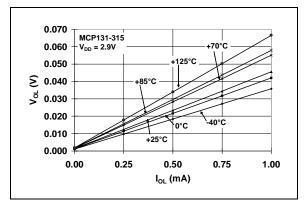


FIGURE 2-17: V_{OL} vs. I_{OL} (MCP131-315 @ $V_{DD} = 2.9V$).

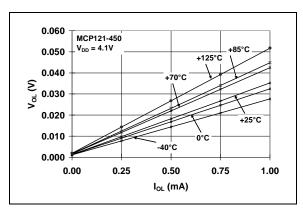


FIGURE 2-18: V_{OL} vs. I_{OL} (MCP121-450 @ $V_{DD} = 4.1$ V).

Note: Unless otherwise indicated, all limits are specified for: V_{DD} = 1V to 5.5V, R_{PU} = 100 k Ω (**MCP121** only; see **Figure 4-1**), T_A = -40°C to +125°C.

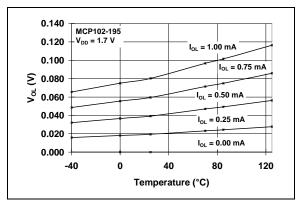


FIGURE 2-19: V_{OL} vs. Temperature (MCP102-195 @ $V_{DD} = 1.7V$).

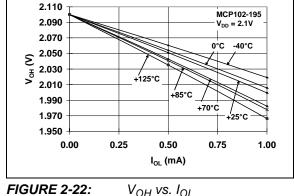


FIGURE 2-22: V_{OH} vs. I_{OL} (MCP102-195 @ $V_{DD} = 2.1V$).

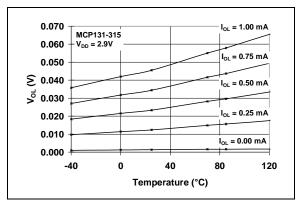


FIGURE 2-20: V_{OL} vs. Temperature (MCP131-315 @ $V_{DD} = 2.9V$).

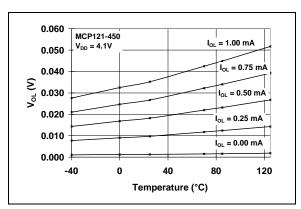


FIGURE 2-21: V_{OL} vs. Temperature (MCP121-450 @ $V_{DD} = 4.1V$).

Note: Unless otherwise indicated, all limits are specified for: V_{DD} = 1V to 5.5V, R_{PU} = 100 k Ω (**MCP121** only; see **Figure 4-1**), T_A = -40°C to +125°C.

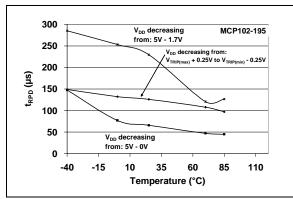


FIGURE 2-23: t_{RPD} vs. Temperature (MCP102-195).

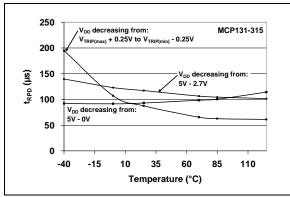


FIGURE 2-24: t_{RPD} vs. Temperature (MCP131-315).

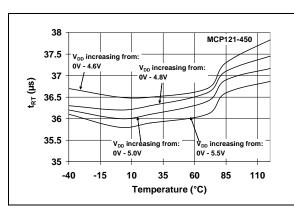


FIGURE 2-25: t_{RPD} vs. Temperature (MCP121-450).

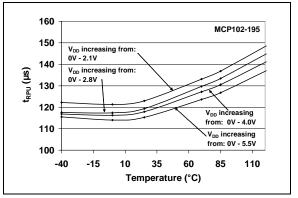


FIGURE 2-26: t_{RPU} vs. Temperature (MCP102-195).

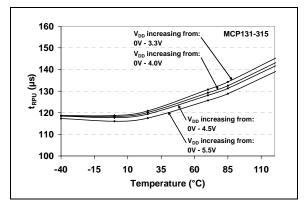


FIGURE 2-27: t_{RPU} vs. Temperature (MCP131-315).

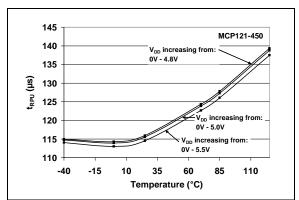


FIGURE 2-28: t_{RPU} vs. Temperature (MCP121-450).

Note: Unless otherwise indicated, all limits are specified for: V_{DD} = 1V to 5.5V, R_{PU} = 100 k Ω (**MCP121** only; see **Figure 4-1**), T_A = -40°C to +125°C.

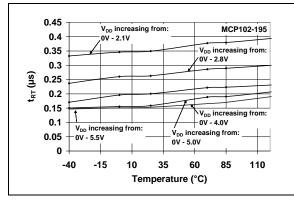


FIGURE 2-29: (MCP102-195).

t_{RT} vs. Temperature

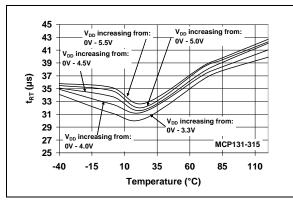


FIGURE 2-30: (MCP131-315).

t_{RT} vs. Temperature

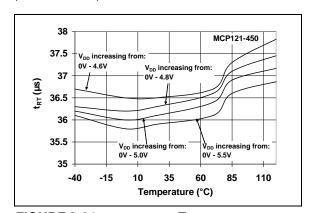


FIGURE 2-31: (MCP121-450).

t_{RT} vs. Temperature

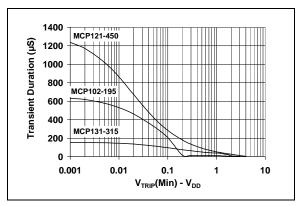


FIGURE 2-32:

Transient Duration vs.

V_{TRIP} (min) - V_{DD}.

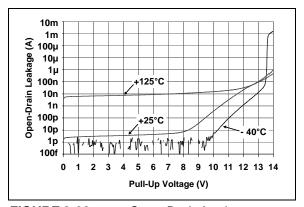


FIGURE 2-33: Open-Drain Leakage Current vs. Voltage Applied to V_{OUT} Pin (MCP121-195).

3.0 PIN DESCRIPTION

The descriptions of the pins are listed in Table 3-1.

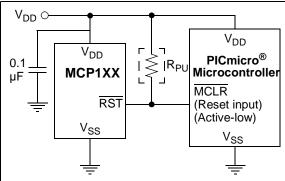
TABLE 3-1: PIN FUNCTION TABLE

Pin No.							
MCP102 MCP121 MCP131	MCP103	Symbol	Function				
1	1	RST	Output State V_{DD} Falling: $H = V_{DD} > V_{TRIP}$ $L = V_{DD} < V_{TRIP}$ V_{DD} Rising: $V_{DD} = V_{TRIP} + V_{$				
2	3	V_{DD}	Positive power supply				
3	2	V_{SS}	Ground reference				

4.0 APPLICATION INFORMATION

For many of today's microcontroller applications, care must be taken to prevent low-power conditions that can cause many different system problems. The most common causes are brown-out conditions, where the system supply drops below the operating level momentarily. The second most common cause is when a slowly decaying power supply causes the microcontroller to begin executing instructions without sufficient voltage to sustain volitile memory (RAM), thus producing indeterminate results. Figure 4-1 shows a typical application circuit.

The MCP102/103/121/131 are voltage supervisor devices designed to keep a microcontroller in reset until the system voltage has reached and stabilized at the proper level for reliable system operation. These devices also operate as protection from brown-out conditions.



Note 1: Resistor R_{PU} may be required with the MCP121 due to the open-drain output. Resistor R_{PU} may not be required with the MCP131 due to the internal pull-up resistor. The MCP102 and MCP103 do not require the external pull-up resistor.

FIGURE 4-1: Typical Application Circuit.

4.1 RST Operation

The $\overline{\text{RST}}$ output pin operation determines how the device can be used and indicates when the system should be forced into reset. To accomplish this, an internal voltage reference is used to set the voltage trip point (V_{TRIP}). Additionally, there is a hysteresis on this trip point.

When the falling edge of V_{DD} crosses this voltage threshold, the reset power-down timer (T_{RPD}) starts. When this delay timer times out, the \overline{RST} pin is forced low.

When the rising-edge of V_{DD} crosses this voltage threshold, the reset power-up timer (T_{RPU}) starts. When this delay timer times out, the \overline{RST} pin is forced high, T_{RPU} is active and there is additional system current.

The actual voltage trip point (V_{TRIPAC}) will be between the minimum trip point ($V_{TRIPMIN}$) and the maximum trip point ($V_{TRIPMAX}$). The hysteresis on this trip point and the delay timer (T_{RPU}) are to remove any "jitter" that would occur on the RST pin when the device V_{DD} is at the trip point.

Figure 4-2 shows the waveform of the \overline{RST} pin as determined by the V_{DD} voltage, while Table 4-1 shows the state of the \overline{RST} pin. The V_{TRIP} specification is for falling V_{DD} voltages. When the V_{DD} voltage is rising, the \overline{RST} will not be driven high until V_{DD} is at $V_{TRIP} + V_{HYS}$. Once V_{DD} has crossed the voltage trip point, there is also a minimal delay time (T_{RPD}) before the \overline{RST} pin is driven low

TABLE 4-1: RST PIN STATES

	State of RS			
Device	V _{DD} <v<sub>TRIP</v<sub>	V _{DD} > V _{TRIP} + V _{HYS}	Ouput Driver	
MCP102	L	Н	Push-pull	
MCP103	L	Н	Push-pull	
MCP121	L	H (1)	Open-drain (1)	
MCP131	Ĺ	H ⁽²⁾	Open-drain (2)	

Note 1: Requires External Pull-up resistor

2: Has Internal Pull-up resistor

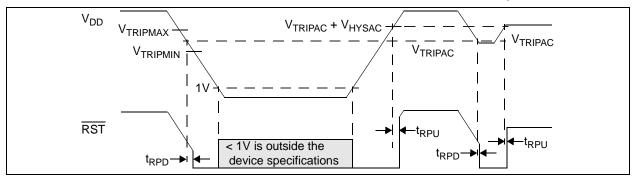


FIGURE 4-2: RST Operation as Determined by the V_{TRIP} and V_{HYS} .

4.2 Negative Going V_{DD} Transients

The minimum pulse width (time) required to cause a reset may be an important criteria in the implementation of a Power-on Reset (POR) circuit. This time is referred to as transient duration, defined as the amount of time needed for these supervisory devices to respond to a drop in $V_{DD}.$ The transient duration time is dependant on the magnitude of $V_{TRIP} - V_{DD}.$ Generally speaking, the transient duration decreases with increases in $V_{TRIP} - V_{DD}.$

Figure 4-3 shows a typical transient duration vs. reset comparator overdrive, for which the MCP102/103/121/131 will not generate a reset pulse. It shows that the farther below the trip point the transient pulse goes, the duration of the pulse required to cause a reset gets shorter. Figure 2-32 shows the transient response characteristics for the MCP102/103/121/131.

A 0.1 μ F bypass capacitor, mounted as close as possible to the V_{DD} pin, provides additional transient immunity (refer to Figure 4-1).

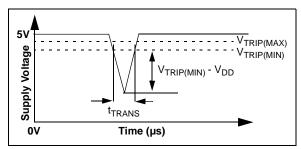


FIGURE 4-3: Example of Typical Transient Duration Waveform.

4.3 Reset Power-up Timer (t_{RPU})

Figure 4-4 illustrates the device current states. While the system is powering down, the device has a low current. This current is dependent on the device V_{DD} and trip point. When the device V_{DD} rises through the voltage trip point (V_{TRIP}), an internal timer starts. This timer consumes additional current until the \overline{RST} pin is driven (or released) high. This time is known as the Reset Power-up Time (t_{RPU}). Figure 4-4 shows when t_{RPU} is active (device consuming additional current).

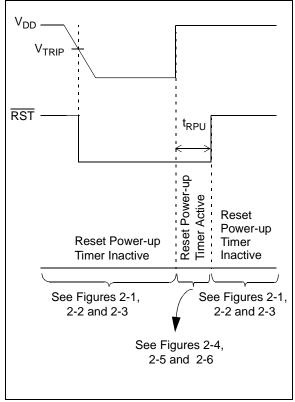


FIGURE 4-4: Reset Power-up Timer Waveform.

4.3.1 EFFECT OF TEMPERATURE ON RESET POWER-UP TIMER (T_{RPU})

The Reset Power-up timer time-out period (t_{RPU}) determines how long the device remains in the reset condition. This is affected by both V_{DD} and temperature. Typical responses for different V_{DD} values and temperatures are shown in Figures 2-26, 2-27 and 2-28.

4.4 Using in PICmicro[®] Microcontroller, ICSP™ Applications (MCP121 only)

Figure 4-5 shows the typical application circuit for using the MCP121 for voltage superviory function when the PICmicro microcontroller will be programmed via the ICSP feature. Additional information is available in TB087, "Using Voltage Supervisors with PICmicro® Microcontroller Systems which Implement In-Circuit Serial Programming TM ", DS91087.

Note: It is recommended that the current into the $\overline{\text{RST}}$ pin be current limited by a 1 k Ω resistor.

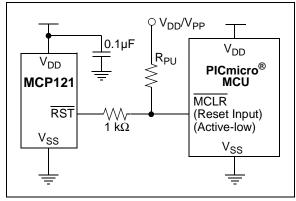
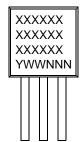


FIGURE 4-5: Typical Application Circuit for PICmicro $^{\textcircled{@}}$ Microcontroller with the ICSPTM feature.

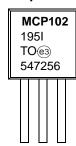
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

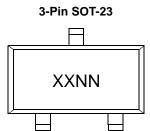
3-Lead TO-92



Example:



Example:



Part Number	MCP1xx =						
Fait Number	MCP1 <u>02</u>	MCP1 <u>03</u>	MCP1 <u>21</u>	MCP131			
MCP1 <u>xx</u> T-195I/TT	JGNN	TGNN	LGNN	KGNN			
MCP1xxT-240ETT	JHNN	THNN	LHNN	KHNN			
MCP1xxT-270E/TT	JJNN	TJNN	LJNN	KJNN			
MCP1xxT-300E/TT	JKNN	TKNN	LKNN	KKNN			
MCP1 <u>xx</u> T-315E/TT	JLNN	TLNN	LLNN	KLNN			
MCP1xxT-450E/TT	JMNN	TMNN	LMNN	KMNN			
MCP1 <u>xx</u> T-475E/TT	JPNN	TPNN	LPNN	KPNN			

Legend: XX...X Customer-specific information

Y Year code (last digit of calendar year)

WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

(e3) Pb-free JEDEC designator for Matte Tin (Sn)

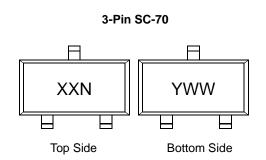
This package is Pb-free. The Pb-free JEDEC designator (e3)

can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available

characters for customer-specific information.

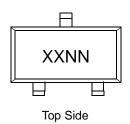
Package Marking Information (Continued)



Example:

Part Number	MCP1xx =						
Part Number	MCP1 <u>02</u>	MCP1 <u>03</u>	MCP1 <u>21</u>	MCP1 <u>31</u>			
MCP1 <u>xx</u> T-195I/LB	BGN	FGN	DGN	CGN			
MCP1xxT-240E/LB	BHN	FHN	DHN	CHN			
MCP1xxT-270E/LB	BJN	FJN	DJN	CJN			
MCP1xxT-300E/LB	BKN	FKN	DKN	CKN			
MCP1xxT-315E/LB	BLN	FLN	DLN	CLN			
MCP1xxT-450E/LB	BMN	FMN	DMN	CMN			
MCP1xxT-475E/LB	BPN	FPN	DPN	CPN			

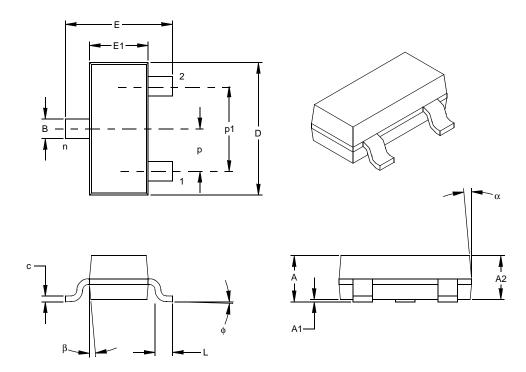




Example:

Part Number	MCP1xx =						
Part Number	MCP1 <u>02</u>	MCP1 <u>03</u>	MCP1 <u>21</u>	MCP1 <u>31</u>			
MCP1 <u>xx</u> T-195I/LB	BGNN	FGNN	DGNN	CGNN			
MCP1xxT-240E/LB	BHNN	FHNN	DHNN	CHNN			
MCP1xxT-270E/LB	BJNN	FJNN	DJNN	CJNN			
MCP1xxT-300E/LB	BKNN	FKNN	DKNN	CKNN			
MCP1xxT-315E/LB	BLNN	FLNN	DLNN	CLNN			
MCP1xxT-450E/LB	BMNN	FMNN	DMNN	CMNN			
MCP1xxT-475E/LB	BPNN	FPNN	DPNN	CPNN			

3-Lead Plastic Small Outline Transistor (TT) (SOT-23)



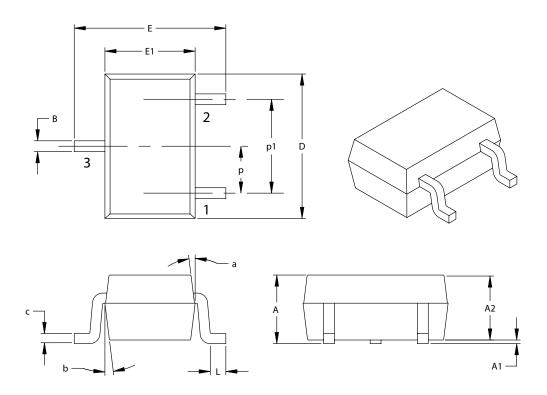
		INCHES*		MILLIMETERS			
Dimensi	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		3			3	
Pitch	р		.038			0.96	
Outside lead pitch (basic)	p1		.076			1.92	
Overall Height	Α	.035	.040	.044	0.89	1.01	1.12
Molded Package Thickness	A2	.035	.037	.040	0.88	0.95	1.02
Standoff §	A1	.000	.002	.004	0.01	0.06	0.10
Overall Width	Е	.083	.093	.104	2.10	2.37	2.64
Molded Package Width	E1	.047	.051	.055	1.20	1.30	1.40
Overall Length	D	.110	.115	.120	2.80	2.92	3.04
Foot Length	L	.014	.018	.022	0.35	0.45	0.55
Foot Angle	ф	0	5	10	0	5	10
Lead Thickness	С	.004	.006	.007	0.09	0.14	0.18
Lead Width	В	.015	.017	.020	0.37	0.44	0.51
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

^{*} Controlling Parameter § Significant Characteristic

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side.
JEDEC Equivalent: TO-236
Drawing No. C04-104

3-Lead Plastic Small Outline Transistor (LB) (SC-70)



	Units	INCH	IES	MILLIMETERS*		
Dimension Limi	Dimension Limits		MAX	MIN	MAX	
Number of Pins		3	3	3		
Pitch	р	.026 BSC.		0.65 BSC.		
Outside lead pitch (basic)	p1	.051 BS	iC.	1.30 BSC.		
Overall Height	Α	.031	.043	0.80	1.10	
Molded Package Thickness	A2	.031	.039	0.80	1.00	
Standoff	A1	.000	.0004	0.00	.010	
Overall Width	Е	.071	.094	1.80	2.40	
Molded Package Width	E1	.045	.053	1.15	1.35	
Overall Length	D	.071	.089	1.80	2.25	
Foot Length	L	.004	.016	0.10	0.41	
Lead Thickness	С	.003	.010	0.08	0.25	
Lead Width	В	.006	.016	0.15	0.40	
Mold Draft Angle Top	a	8°	12°	8°	12°	
Mold Draft Angle Bottom	b	8°	12°	8°	12°	

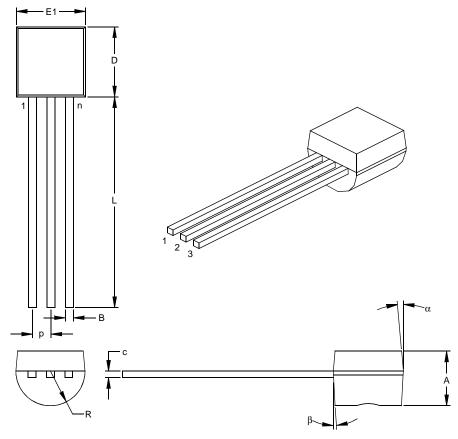
^{*}Controlling Parameter

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side.

JEITA (EIAJ) Equivalent: SC70 Drawing No. C04-104

3-Lead Plastic Transistor Outline (TO) (TO-92)



	Units	INCHES*			MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		3			3	
Pitch	р		.050			1.27	
Bottom to Package Flat	Α	.130	.143	.155	3.30	3.62	3.94
Overall Width	E1	.175	.186	.195	4.45	4.71	4.95
Overall Length	D	.170	.183	.195	4.32	4.64	4.95
Molded Package Radius	R	.085	.090	.095	2.16	2.29	2.41
Tip to Seating Plane	L	.500	.555	.610	12.70	14.10	15.49
Lead Thickness	С	.014	.017	.020	0.36	0.43	0.51
Lead Width	В	.016	.019	.022	0.41	0.48	0.56
Mold Draft Angle Top	α	4	5	6	4	5	6
Mold Draft Angle Bottom	β	2	3	4	2	3	4

^{*}Controlling Parameter

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: TO-92

Drawing No. C04-101

5.2 Product Tape and Reel Specifications

FIGURE 5-1: EMBOSSED CARRIER DIMENSIONS (8, 12, 16 AND 24 MM TAPE ONLY)

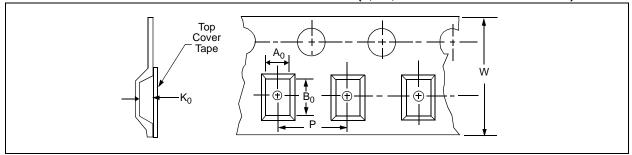
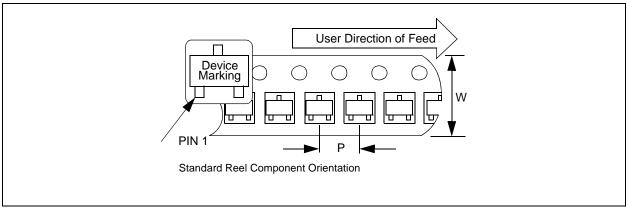


TABLE 1: CARRIER TAPE/CAVITY DIMENSIONS

Case Package Outline Type		е	Carrier Dimensions		Cavity Dimensions			Output Quantity	Reel Diameter in
		W mm	P mm	A0 mm	B0 mm	K0 mm	Units	mm	
TT	SOT-23	3L	8	4	3.15	2.77	1.22	3000	180
LB	SC-70	3L	8	4	2.4	2.4	1.19	3000	180

FIGURE 5-2: 3-LEAD SOT-23/SC70 DEVICE TAPE AND REEL SPECIFICATIONS



Device Marking

Back Tape

Note: Bent leads are for Tape and Reel only.

NOTES:

APPENDIX A: REVISION HISTORY

Revision B (March 2005)

The following is the list of modifications:

- Added Section 4.4 "Using in PICmicro® Microcontroller, ICSP™ Applications (MCP121 only)" on using the MCP121 in PICmicro microcontroller ICSP applications.
- 2. Added V_{ODH} specifications in **Section 1.0** "**Electrical Characteristics**" (for ICSP applications).
- 3. Added Figure 2-33.
- 4. Updated SC-70 package markings and added Pb-free marking information to **Section 5.0** "Packaging information".
- 5. Added Appendix A: "Revision History".

Revision A (August 2004)

· Original Release of this Document.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

DARTNO - V	vvv v / vv	Exa	Examples:			
PART NO. — X Device Tape/Re Option	eel Monitoring Temperature Package n Options Range	a)	MCP102T-195I/TT:	Tape and Reel, 1.95V MicroPower Voltage Supervisor, push-pull, -40°C to +85°C, SOT-23B-3 package.		
Device:	MCP102: MicroPower Voltage Supervisor, push-pull MCP102T: MicroPower Voltage Supervisor, push-pull (Tape and Reel) MCP103: MicroPower Voltage Supervisor, push-pull MCP103T: MicroPower Voltage Supervisor, push-pull	b)	MCP102-300E/TO:			
	(Tape and Reel) MCP121 MicroPower Voltage Supervisor, open-drain MCP121T: MicroPower Voltage Supervisor, open-drain (Tape and Reel) MCP131 MicroPower Voltage Supervisor, open-drain MCP131T: MicroPower Voltage Supervisor, open-drain (Tape and Reel)	a)	MCP103T-270E/TT:	Tape and Reel, 2.70V MicroPower Voltage Supervisor, push-pull, -40°C to +125°C, SOT-23B-3 package.		
Monitoring Options:	195 = 1.90V 240 = 2.32V 270 = 2.63V 300 = 2.93V	b)	MCP103T-475E/LB:	Tape and Reel, 4.75V MicroPower Voltage Supervisor, push-pull, -40°C to +125°C, SC-70-3 package.		
Temperature Range:	315 = 3.08V 450 = 4.38V 475 = 4.63V I = -40°C to +85°C (MCP11X-195 only)	a)	MCP121T-315I/LB:	Tape and Reel, 3.15V MicroPower Voltage Supervisor, open-drain, -40°C to +125°C, SC-70-3 package.		
Package:	E = -40°C to +125°C (Except MCP11X-195 only) TT = SOT-23B, 3-lead LB = SC-70, 3-lead TO = TO-92, 3-lead	b)	MCP121-300E/TO:	. •		
		a)	MCP131T-195I/TT:	Tape and Reel, 1.95V MicroPower Voltage Supervisor, open-drain, -40°C to +85°C, SOT-23B-3 package.		
		b)	MCP131-300E/TO:	3.00V MicroPower Voltage Supervisor, open-drain, -40°C to +125°C, TO-92-3 package.		

NOTES:

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NCP305LSQ31T1G NCP305LSQ32T1G NCP308MT250TBG NCP308SN300T1G NCP391FCALT2G NCV303LSN42T1G CAT1161LI-25-

G CAT853STBI-T3 MAX1232CPA MAX705CPA CAT1026LI-30-G CAT1320LI-25-G CAT872-30ULGT3 NCP304HSQ18T1G

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NCV303LSN27T1G NCV33161DMR2G TC54VN2402EMB713 MCP1316T-44NE/OT MCP1316MT-45GE/OT MCP1316MT-23LI/OT

MCP1316T-26LE/OT MAX8997EWW+ MAX821RUS+T MAX6725AKASYD3-LF-T MAX809SEUR MAX708TEPA
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